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Vishay Siliconix

N-Channel 100 V (D-S) MOSFET

PRODUCT	SUMMARY		
V _{DS} (V)	R _{DS(on)} (Ω) MAX.	I _D (A)	Q _g (TYP.)
100	0.0093 at V _{GS} = 10 V	42.8	33 nC
100	0.0100 at V _{GS} = 7.5 V	33	33110

Thin-Lead TO-220 FULLPAK



Ordering Information:

SUA70090E-E3 (lead (Pb)-free and halogen-free)

FEATURES

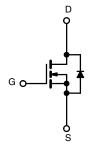
- ThunderFET® power MOSFET
- Q_{gd} / Q_{gs} ratio < 1 optimizes switching characteristics



- 100 % Rg and UIS tested
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

APPLICATIONS

- Power supply
 - Secondary synchronous rectification
- DC/DC converter
- Power tools
- · Motor drive switch
- DC/AC inverter



N-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS (T _C = 25 °C, unless otherwise noted)						
PARAMETER		SYMBOL	LIMIT	UNIT		
Drain-Source Voltage		V _{DS}	100	V		
Gate-Source Voltage	V _{GS}	± 20				
Continuous Drain Current (T _{.I} = 150 °C)	T _C = 25 °C	,	42.8			
Continuous Drain Current (1, = 150 °C)	T _C = 70 °C	I _D	34.2	_		
Pulsed Drain Current (t = 100 μs)	I _{DM}	120	A			
Avalanche Current	I _{AS}	40				
Single Avalanche Energy ^a	L = 0.1 mH	E _{AS}	80	mJ		
Maniana Dania Diadia king 2	T _C = 25 °C	В	35.7	W		
Maximum Power Dissipation ^a	T _C = 70 °C	$ P_D$	22.9			
Operating Junction and Storage Temperature Range		T _J , T _{stg}	-55 to +150	°C		

THERMAL RESISTANCE RATINGS			
PARAMETER	SYMBOL	LIMIT	UNIT
Junction-to-Ambient (PCB Mount) ^b	R _{thJA}	60	°C/W
Junction-to-Case (Drain)	R _{th,IC}	3.5	- C/VV

Notes

- a. Duty cycle ≤ 1 %.
- b. When mounted on 1" square PCB (FR4 material).



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PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Static						
Drain-Source Breakdown Voltage	V _{DS}	$V_{GS} = 0 \text{ V}, I_D = 250 \mu\text{A}$	100	-	-	
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_D = 250 \mu A$	2	-	4	\
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$	-	-	± 250	nA
		V _{DS} = 100 V, V _{GS} = 0 V	-	-	1	
Zero Gate Voltage Drain Current	I _{DSS}	V_{DS} = 100 V, V_{GS} = 0 V, T_J = 125 °C	-	-	150	μА
		$V_{DS} = 100 \text{ V}, V_{GS} = 0 \text{ V}, T_J = 175 ^{\circ}\text{C}$	-	-	5	mA
On-State Drain Current ^a	I _{D(on)}	$V_{DS} \ge 10 \text{ V}, V_{GS} = 10 \text{ V}$	50	-	-	Α
Drain Course On State Resistance 3	J	$V_{GS} = 10 \text{ V}, I_D = 20 \text{ A}$	-	0.0077	0.0093	V nA μA mA
Drain-Source On-State Resistance ^a	R _{DS(on)}	V _{GS} = 7.5 V, I _D = 15 A	-	0.0083	0.0100	
Forward Transconductance ^a	9 _{fs}	V _{DS} = 15 V, I _D = 10 A	-	38	-	S
Dynamic ^b						
Input Capacitance	C _{iss}		-	1950	-	pF
Output Capacitance	C _{oss}	V _{GS} = 0 V, V _{DS} = 50 V, f = 1 MHz	-	845	-	
Reverse Transfer Capacitance	C _{rss}		-	54	-	
Total Gate Charge ^c	Q_g		-	33	50	
Gate-Source Charge ^c	Q _{gs}	$V_{DS} = 50 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 20 \text{ A}$	-	8.8	-	nC
Gate-Drain Charge ^c	Q_{gd}		-	7.5	-	
Gate Resistance	R_g	f = 1 MHz	0.7	3.5	7	Ω
Turn-On Delay Time ^c	t _{d(on)}		-	15	30	
Rise Time ^c	t _r	$V_{DD} = 50 \text{ V, } R_L = 5 \Omega$ $I_D \cong 10 \text{ A, } V_{GEN} = 10 \text{ V, } R_g = 1 \Omega$	-	27	54	ns
Turn-Off Delay Time ^c	t _{d(off)}		-	36	72	
Fall Time ^c	t _f		-	45	90	
Drain-Source Body Diode Ratings ar	nd Characteri	stics ^b (T _C = 25 °C)				
Pulsed Current (t = 100 μs)	I _{SM}		-	-	120	Α
Forward Voltage ^a	V _{SD}	I _F = 10 A, V _{GS} = 0 V	-	0.8	1.5	V
Reverse Recovery Time	t _{rr}		-	77	116	ns
Peak Reverse Recovery Charge	I _{RM(REC)}	$I_F = -10 \text{ A}, \text{ dI/dt} = 100 \text{ A/}\mu\text{s}$	-	4.2	6.3	Α
Reverse Recovery Charge	Q _{rr}		-	145	365	nC

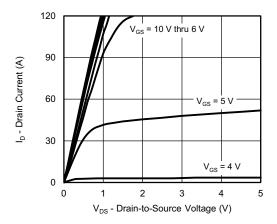
Notes

- a. Pulse test; pulse width $\leq 300~\mu s,$ duty cycle $\leq 2~\%.$
- b. Guaranteed by design, not subject to production testing.
- c. Independent of operating temperature.

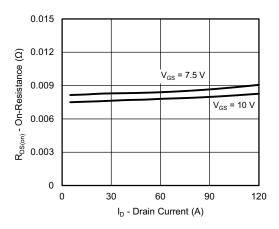
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



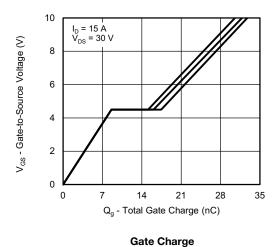
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)

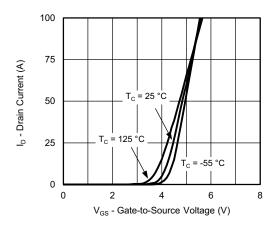


Output Characteristics

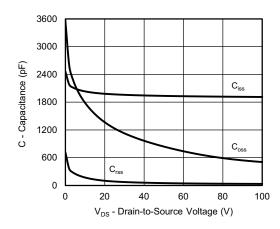


On-Resistance vs. Drain Current

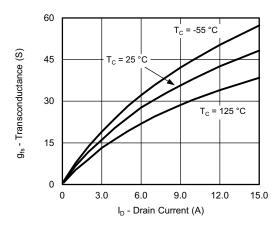




Transfer Characteristics



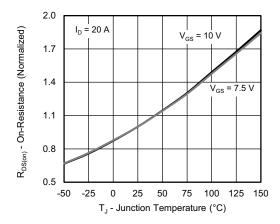
Capacitance



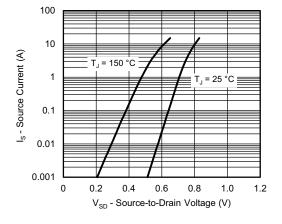
Transconductance



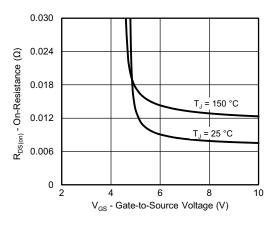
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



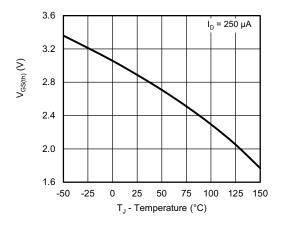
On-Resistance vs. Junction Temperature



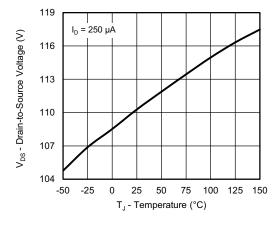
Source Drain Diode Forward Voltage



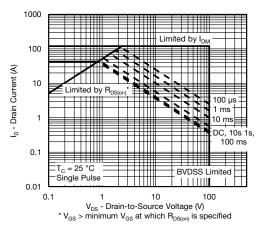
On-Resistance vs. Gate-to-Source Voltage



Threshold Voltage



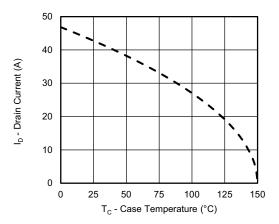
Drain Source Voltage vs. Junction Temperature



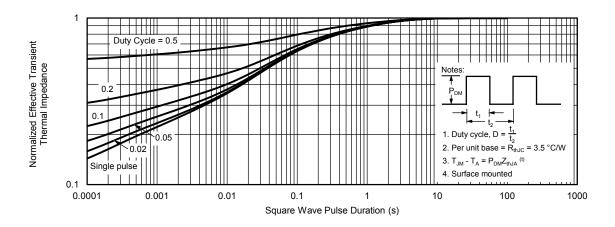
Safe Operating Area



THERMAL RATINGS (T_A = 25 °C, unless otherwise noted)



Current De-Rating



Normalized Thermal Transient Impedance, Junction-to-Case

Note

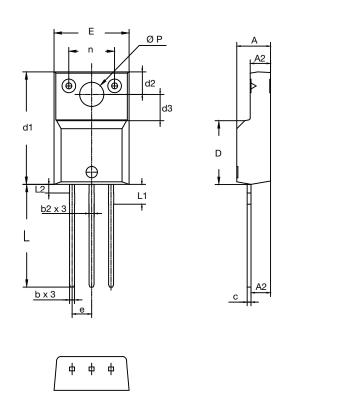
- · The characteristics shown in the two graphs
 - Normalized Transient Thermal Impedance Junction to Ambient (25 °C)
 - Normalized Transient Thermal Impedance Junction to Case (25 °C)

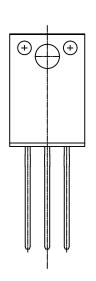
are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions.

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppq?65438.



TO-220 FULLPAK Thin Lead





SYMBOL	DIMENSIONS			
	MILLIMETERS		INCHES	
	MIN.	MAX.	MIN.	MAX.
Α	4.30	4.70	0.169	0.185
A1	2.50	2.90	0.098	0.114
A2	2.50	2.70	0.098	0.106
b	0.60	0.80	0.024	0.031
b2	0.60	0.90	0.024	0.035
С	-	0.60	-	0.024
D	8.30	8.70	0.327	0.342
d1	14.70	15.30	0.579	0.602
d2	2.90	3.10	0.114	0.122
d3	3.40	3.60	0.134	0.142
Е	9.70	10.30	0.382	0.406
е	2.50	2.70	0.098	0.106
L	13.40	13.80	0.528	0.543
L1	2.50	2.80	0.098	0.110
L2	=	1.20	-	0.047
n	6.05	6.15	0.238	0.242
ØP	3.00	3.40	0.118	0.134

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